

# Kazuhisa Torigoe

## List of Publications by Year in descending order

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5  
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2257263

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2053342

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#	ARTICLE	IF	CITATIONS
1	Formation of thermal donor enhanced by oxygen precipitation in silicon crystal. AIP Advances, 2020, 10, .	0.6	8
2	Enhanced diffusion of boron by oxygen precipitation in heavily boron-doped silicon. Journal of Applied Physics, 2017, 121, .	1.1	6
3	Enhanced diffusion of oxygen depending on Fermi level position in heavily boron-doped silicon. Journal of Applied Physics, 2014, 116, 193503.	1.1	5
4	Formulation of mobile dislocation density in oxygen-precipitated silicon by crystal plasticity model. Japanese Journal of Applied Physics, 2019, 58, 031002.	0.8	2
5	Theoretical study of stress impact on formation enthalpy and thermal equilibrium concentration of impurities and dopants in Si single crystal. Journal of Crystal Growth, 2021, 572, 126284.	0.7	1